



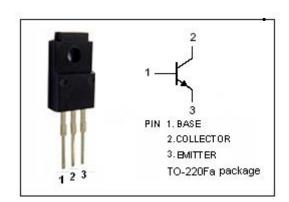
isc Silicon NPN Power Transistor

DESCRIPTION

- · Collector-Base Breakdown Voltage-
- : V_{(BR)CBO}= 900V(Min.)
- Wide Area of Safe Operation
- · High Speed Switching
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

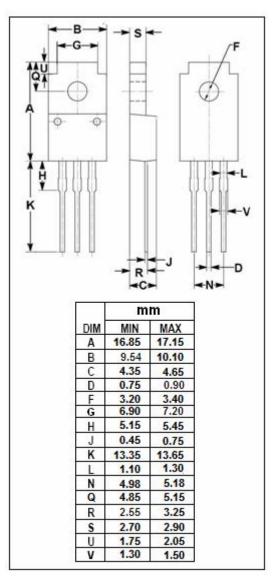


· Designed for high speed switching applications.



ABSOLUTE MAXIMUM RATINGS (Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{СВО}	Collector-Base Voltage	900	V
V _{CES}	Collector-Emitter Voltage	900	V
V _{CEO}	Collector-Emitter Voltage	800	V
V _{EBO}	Emitter-Base Voltage	7	V
Ic	Collector Current-Continuous	1	А
Ісм	Collector Current-Peak	2	А
I _B	Base Current-Continuous	0.3	А
Pc	Collector Power Dissipation @T _a =25℃	2	
	Collector Power Dissipation @T _C =25°C	30	W
T _j	Junction Temperature	150	$^{\circ}$ C
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$





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2SC4004

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

1c-25 C unless otherwise specified									
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 1mA; I _B = 0	800			V			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 0.2A; I _B = 40mA			1.5	V			
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 0.2A; I _B = 40mA			1.0	V			
І _{СВО}	Collector Cutoff Current	V _{CB} = 900V; I _E = 0			50	μА			
I _{EBO}	Emitter Cutoff Current	V _{EB} = 7V; I _C = 0			50	μА			
h _{FE-1}	DC Current Gain	I _C = 50mA; V _{CE} = 5V	6						
h _{FE-2}	DC Current Gain	I _C = 0.5A; V _{CE} = 5V	3						
f⊤	Current-Gain—Bandwidth Product	Ic= 50mA; VcE= 10V; f= 1MHz		4		MHz			
Switching Times									
ton	Turn-on Time				1.0	μ S			
ts	Storage Time	I_C = 0.2A; I_{B1} = 0.04A; I_{B2} = -0.04A; V_{CC} = 250V			3.0	μ \$			
t _f	Fall Time				1.0	μS			

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